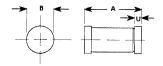


SANTA ANA, CA

SCOTTSDALE, AZ For more information call: (602) 941-6300

MLL5817, MLL5818, MLL5819 and MLL6650

1 AMP SCHOTTKY RECTIFIERS



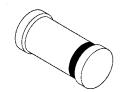


Figure 1

DIM.	MILLIN	IETERS	INCHES		
	MIN.	MAX.	MIN.	MAX.	
Α	4.80	5.20	.189	.205	
В	2.39	2.66	.094	.105	
U	0.41	0.55	.016	.022	

DO-213AB

Mechanical Characteristics

CASE: Hermetically sealed glass with solder contact tabs at each end.

FINISH: All external surfaces are corrosion resistant, readily solderable.

POLARITY:

Banded end is cathode.

THERMAL RESISTANCE:

50°C/ Watt typical junction to end caps. (See Power Derating Curve).

MOUNTING POSITION: Any.

Description / Features

- SCHOTTKY BARRIER RECTIFIER
- . GUARD RING PROTECTION
- LOW FORWARD VOLTAGE
- HIGH CURRENT CAPABILITY
- EXTREMELY FAST SWITCHING TIME
- PENDING QUALIFICATION TO NEW MIL-S-19500/586

Maximum Ratings

Storage Temperature (T_{STG}): -65°C to +150°C Operating Junction Temperature (T_{S}): -65°C to +150°C Operating End Cap Temperature (T_{EC}): -65°C to +125°C Maximum Thermal Resistance (T_{EC}): 45°C/W

Application

This surface mount series of Schottky 1.0 Amp rated rectifiers provides a metal to silicon barrier rectifier with majority carrier conduction and low forward voltage, using oxide passivation and diffused guard ring protection. They are ideally suited as rectifiers in low-voltage, high-frequency inverters, free wheeling diodes, switch mode power supplies, and polarity protection.

*Electrical Characteristics @ 25° C

	MAXIMUM FORWARD VOLTAGE (V _F) (Note 1)			PEAK REVERSE VOLTAGE		SURGE CURRENT MAX.	PEAK REVERSE CURRENT	JUNCTION CAPACITANCE TYPICAL
MICROSEMI PART	I _F = 0.1A	I _F = 1.0A	I _F = 3.0A	VRRM @ (See Note 2)	(See Note 3)	IFSM (See Note 4)	RM (See Note 5)	C _J @ V _R = 5 _V
NUMBER	VOLTS	VOLTS	VOLTS	VOLTS	A	A	mA	pF
MLL5817 MLL5818 MLL5819 MLL6650	.36 .39 .39 .39	.45 .55 .55	.65 .85 .85 .80	20 30 40 45	1.0 1.0 1.0 1.0	50 50 50 50	1.0 1.0 1.0 1.0	105 70 70 70

Note 1: 300µsec pulse, duty cycle = 2%

Note 2: Derate linearly at 1.8 V/°C above $T_{EC} = 125$ °C

Note 3: Derate linearly at 14 mA/°C above $T_{FC} = 80$ °C

Note 4: 8.3 msec, 1/2 sine, $T_{FC} = 70^{\circ}C$

Note 5: I_{RM} tested at V_{RRM}

MLL5817, MLL5818, MLL5819 and MLL6650

Figures 1-3 for MLL5817

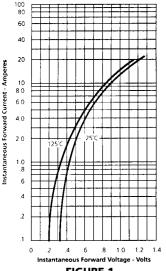


FIGURE 1
Typical Forward Characteristics

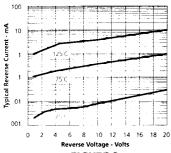


FIGURE 2
Typical Reverse Characteristics

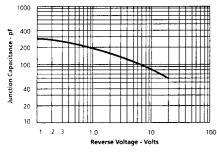


FIGURE 3
Typical Junction Capacitance

Figures 4-6 for MLL5818, MLL5819 & MLL6650

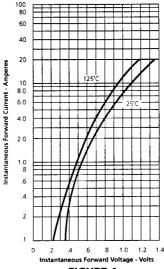


FIGURE 4
Typical Forward Characteristics

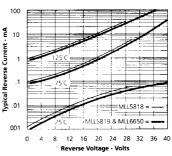


FIGURE 5
Typical Reverse Characteristics

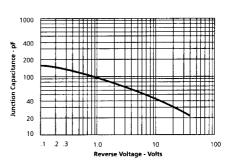


FIGURE 6
Typical Junction Capacitance